V10D45C

www.vishay.com

Vishay General Semiconductor

## Dual Low-Voltage TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.34$  V at  $I_F = 2.5$  A





### ADDITIONAL RESOURCES



ISHA

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 5.0 A			
V <sub>RRM</sub>	45 V			
I <sub>FSM</sub>	100 A			
$V_F$ at $I_F = 5.0$ A	0.41 V			
T <sub>J</sub> max.	150 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3\_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V10D45C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	45	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	10	А	
	per diode		5		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	100	А	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	

Revision: 22-Jan-2020

Document Number: 89992 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <a href="http://www.vishay.com/doc?91000">www.vishay.com/doc?91000</a>

1

AUTOMOTIVE GRADE Available

> RoHS COMPLIANT

HALOGEN FREE

## V10D45C



www.vishay.com

## Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.44	-	V	
	I <sub>F</sub> = 5.0 A			0.50	0.58		
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.34	-		
	I <sub>F</sub> = 5.0 A			0.41	0.50		
Reverse current per diode	$V_{R} = 45 V$ $T_{A} = 25 °C$ $T_{A} = 125 °C$	I <sub>R</sub> <sup>(2)</sup>	-	500	μA		
		T <sub>A</sub> = 125 °C	'R (=/	3	15	mA	

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V10D45C	UNIT	
Typical thermal resistance	per diode	R <sub>θJC</sub>	3.5	°C/W	
	per device		2.5		
	per device	R <sub>0JA</sub> (1)(2)	48		

#### Notes

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

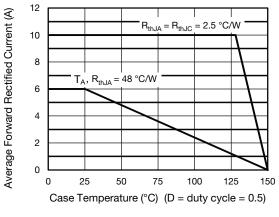
<sup>(2)</sup> Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V10D45C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V10D45CHM3_A/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

#### Note

(1) AEC-Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)





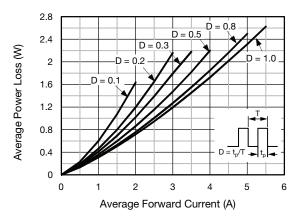


Fig. 2 - Forward Power Loss Characteristics Per Diode

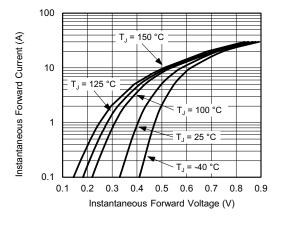
Revision: 22-Jan-2020

Document Number: 89992

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

## V10D45C

## Vishay General Semiconductor



www.vishay.com

SHAY

Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

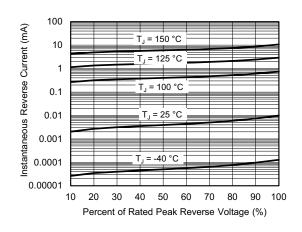


Fig. 4 - Typical Reverse Characteristics Per Diode

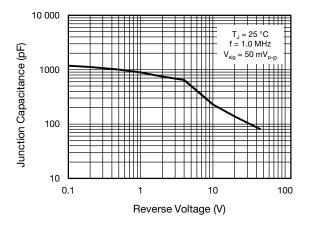


Fig. 5 - Typical Junction Capacitance Per Diode

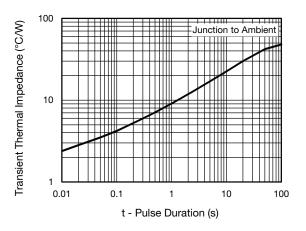


Fig. 6 - Typical Transient Thermal Impedance Per Diode

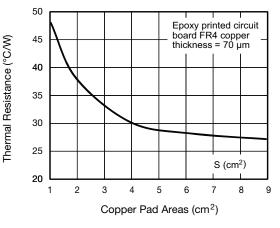


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. **Copper Pad Areas** 

### Revision: 22-Jan-2020

Document Number: 89992 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <a href="http://www.vishay.com/doc?91000">www.vishay.com/doc?91000</a>

3

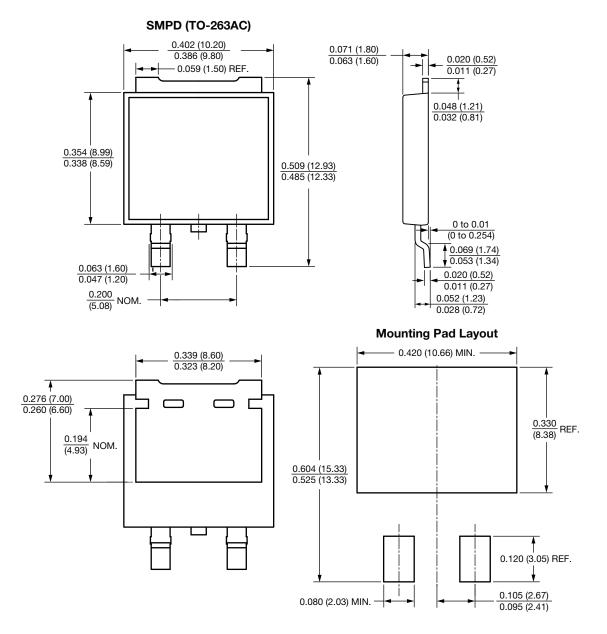


www.vishay.com

**VISHAY** 

Vishay General Semiconductor

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



Revision: 22-Jan-2020

Document Number: 89992

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

4



www.vishay.com

Legal Disclaimer Notice

Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2019 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573 NTE6081